IEEE EDS Kansai Chapter Awards 2022

■ IEEE EDS Kansai Chapter of the Year Award

Author: **Keita Tachiki**,

Title: Improvement of Both n- and p-Channel Mobilities in 4H-SiC MOSFETs by High-Temperature N2 Annealing   [IEEE TED]

Coauthors: **Keita Tachiki**, Tsunenobu Kimoto

Affiliation: Kyoto University

■ IEEE EDS Kansai Chapter MFSK Award (Student Award)

Author: **Tomohiro Kuyama**[1],

Title: Evaluation methodology for assessment of dielectric degradation and breakdown dynamics using time dependent impedance spectroscopy (TDIS)   [IEEE IRPS]

Coauthors: **Tomohiro Kuyama**[1], Keiichiro Urabe, and Koji Eriguchi

Affiliation: Kyoto University
(*currently, TOKYO ELECTRON MIYAGI Ltd.)